SOT223 PNP SILICON PLANAR HIGH CURRENT (HIGH PERFORMANCE) POWER TRANSISTOR

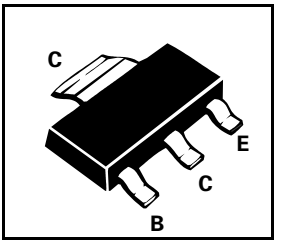
FZT968

ISSUE 3 – OCTOBER 1995

FEATURES

* Extremely low equivalent on-resistance; **$R_{CE(sat)}$ 44mΩ at 5A**
* 6 Amps continuous current (Up to 20 Amps peak)
* High gain and very low saturation voltage

PARTMARKING DETAIL – FZT968



ABSOLUTE MAXIMUM RATINGS.

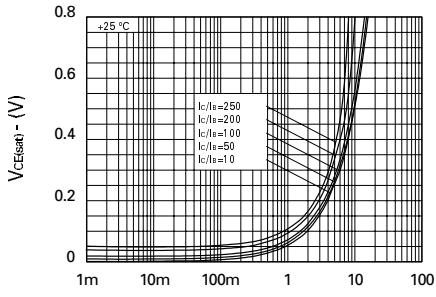
PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V_{CBO}	-15	V
Collector-Emitter Voltage	V_{CEO}	-12	V
Emitter-Base Voltage	V_{EBO}	-6	V
Peak Pulse Current	I_{CM}	-20	A
Continuous Collector Current	I_C	-6	A
Power Dissipation at T_{amb}=25°C	P_{tot}	3	W
Operating and Storage Temperature Range	T_j:T_{stg}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (at T_{amb} = 25°C unless otherwise stated)

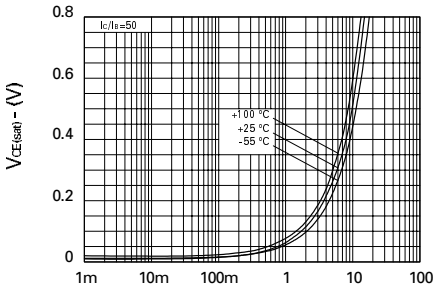
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Breakdown Voltages	$V_{(BR)CBO}$	-15	-28		V	I_C=-100μA
	$V_{(BR)CEO}$	-12	-20		V	I_C=-10mA*
	$V_{(BR)EBO}$	-6	-8		V	I_E=-100μA
Collector Cut-Off Current	I_{CBO}			-10 -1.0	nA μA	V_{CB}=-12V V_{CB}=-12V, T_{amb}=100°C
Emitter Cut-Off Current	I_{EBO}			-10	nA	V_{EB}=-6V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-65 -132 -360	-130 -170 -450	mV mV mV	I_C=-500mA, I_B=-5mA* I_C=-2A, I_B=-50mA* I_C=-6A, I_B=-250mA*
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		-1050	-1200	mV	I_C=-6A, I_B=-250mA*
Base-Emitter Turn-On Voltage	$V_{BE(on)}$		-870	-1050	mV	I_C=-6A, V_{CE}=-1V*
Static Forward Current Transfer Ratio	h_{FE}	300 300 200 150	450 450 300 240 50	1000		I_C=-10mA, V_{CE}=-1V* I_C=-500mA, V_{CE}=-1V* I_C=-5A, V_{CE}=-1V* I_C=-10A, V_{CE}=-1V* I_C=-20A, V_{CE}=-1V*
Transition Frequency	f_T		80		MHz	I_C=-100mA, V_{CE}=-10V f=50MHz
Output Capacitance	C_{obo}		161		pF	V_{CB}=-20V, f=1MHz
Switching Times	t_{on} t_{off}		120 116		ns ns	I_C=-4A, I_{B1}=-400mA I_{B2}=400mA, V_{CC}=-10V

*Measured under pulsed conditions. Pulse width=300μs. Duty cycle ≤2%
Spice parameter data is available upon request for this device

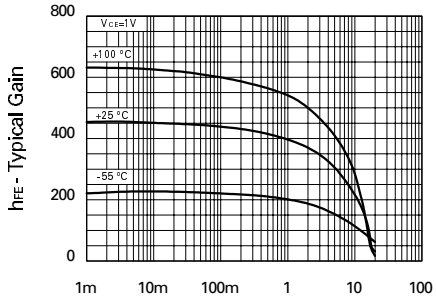
TYPICAL CHARACTERISTICS



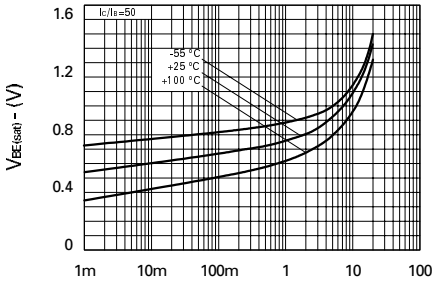
$V_{CE(sat)}$ v I_C



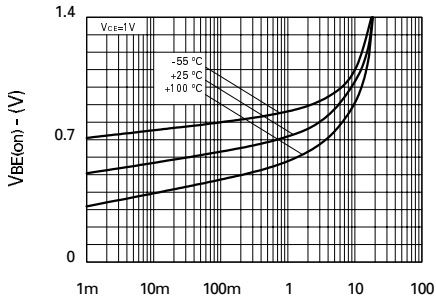
$V_{CE(sat)}$ v I_C



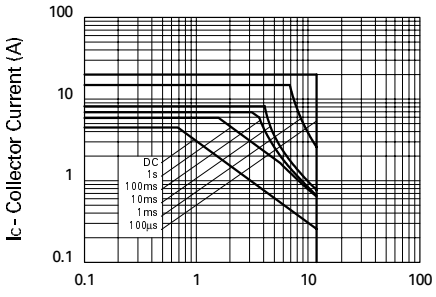
h_{FE} v I_C



$V_{BE(sat)}$ v I_C



$V_{BE(on)}$ v I_C



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